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## 30V N-Channel Power MOSFET



**SOT-23** 



#### Pin Definition:

- 1. Gate
- 2. Source
- 3. Drain

### **Key Parameter Performance**

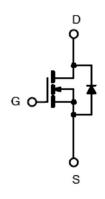
Parameter		Value	Unit	
$V_{DS}$		30	V	
R <sub>DS(on)</sub> (max)	$V_{GS} = 10V$	24	m	
	$V_{GS} = 4.5V$	34		
$Q_g$		4.1	nC	

### **Ordering Information**

Part No.	Package	Packing
TSM240N03CX RFG	SOT-23	3kpcs / 7_Reel

<sup>✓</sup> Note: `G\_denotes for Halogen- and Antimony-free as those which
contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl)
and <1000ppm antimony compounds
</p>

#### **Block Diagram**



N-Channel MOSFET

#### **Absolute Maximum Ratings** (T<sub>C</sub> = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		$V_{ extsf{DS}}$	30	V
Gate-Source Voltage		$V_{GS}$	±20	V
Continuous Drain Current	T <sub>C</sub> = 25°C	- I <sub>D</sub>	6.5	Α
	T <sub>C</sub> = 100°C		4.1	Α
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	26	Α
Single Pulse Avalanche Energy (Note 2)		E <sub>AS</sub>	32	mJ
Power Dissipation @ T <sub>C</sub> = 25°C		$P_{D}$	1.56	W
Operating Junction Temperature		$T_J$	150	°C
Storage Temperature Range		T <sub>STG</sub>	-55 to +150	°C

#### **Thermal Performance**

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Ambient	R∄⊎A	80	°C/W



## 30V N-Channel Power MOSFET



**Electrical Specifications** (T<sub>C</sub> = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV <sub>DSS</sub>	30			٧
B : 0	$V_{GS} = 10V, I_D = 6A$	RDS(on)		17	24	m
Drain-Source On-State Resistance	$V_{GS} = 4.5V, I_D = 4A$			22	34	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	1.2	1.4	2.5	٧
	$V_{DS} = 30V, V_{GS} = 0V$				1	
Zero Gate Voltage Drain Current	V <sub>DS</sub> = 24V, T <sub>J</sub> = 125°C	l <sub>DSS</sub>			10	μΑ
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	μΑ
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_{D} = 4A$	g <sub>fs</sub>		6.5		S
Dynamic				l		
Total Gate Charge (Note 3,4)		$Q_g$		4.1		nC
Gate-Source Charge (Note 3,4)	$V_{DS} = 15V, I_{D} = 6A,$	$Q_{gs}$		1		
Gate-Drain Charge (Note 3,4)	$V_{GS} = 4.5V$	$Q_{gd}$		2.1		
Input Capacitance		C <sub>iss</sub>		345		
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$	C <sub>oss</sub>		55		pF
Reverse Transfer Capacitance	f = 1.0MHz	C <sub>rss</sub>		32		
Switching						
Turn-On Delay Time (Note 3,4)		t <sub>d(on)</sub>		2.8		
Turn-On Rise Time (Note 3,4)	$V_{DD} = 15V, I_{D} = 1A,$	t <sub>r</sub>		7.2		
Turn-Off Delay Time (Note 3,4)	$V_{GS} = 10V, R_G = 6$	t <sub>d(off)</sub>		15.8		ns
Turn-Off Fall Time (Note 3,4)		t <sub>f</sub>		4.6		
Source-Drain Diode Ratings and Ch	aracteristic			l		
Maximum Continuous Drain-Source	Integral reverse diode in the MOSFET	ı			6.5	Α
Diode Forward Current		I <sub>S</sub>			0.0	
Maximum Pulse Drain-Source Diode		I <sub>SM</sub>			26	Α
Forward Current						
Diode-Source Forward Voltage	$V_{GS} = 0V, I_{S} = 1A$	$V_{SD}$			1	V

#### Note:

- 1. Pulse width limited by safe operating area
- 2. L = 1mH,  $I_{AS} = 8A$ ,  $V_{DD} = 25V$ ,  $R_G = 25$ , Starting  $T_J = 25$ °C
- 3. Pulse test: pulse width #300µs, duty cycle #2%
- 4. Switching time is essentially independent of operating temperature.

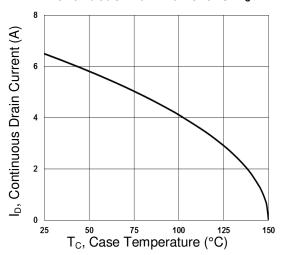


## 30V N-Channel Power MOSFET

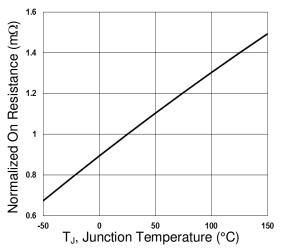


#### **Electrical Characteristics Curve**

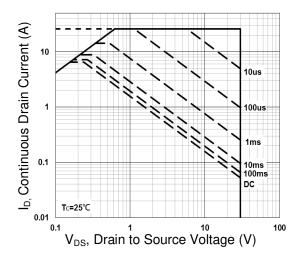
#### Continuous Drain Current vs. Tc

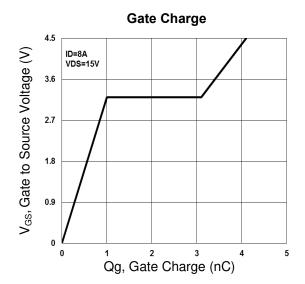


#### On-Resistance vs. Junction Temperature

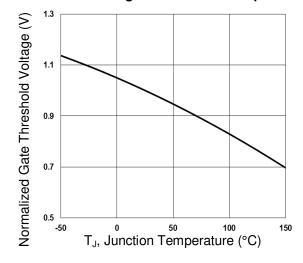


#### **Maximum Safe Operating Area**

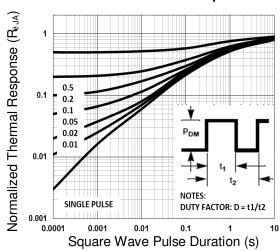




#### Threshold Voltage vs. Junction Temperature



#### **Normalized Thermal Transient Impedance Curve**

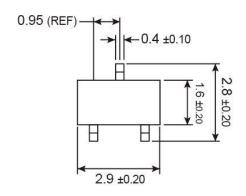


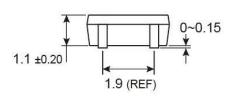


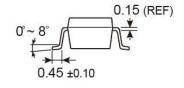
## 30V N-Channel Power MOSFET



## **SOT-23 Mechanical Drawing**







Unit: Millimeters

## **Marking Diagram**



24 = Device Code

Y = Year Code

M = Month Code for Halogen Free Product
 (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep,
 X=Oct, Y=Nov, Z=Dec)

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L = Lot Code

Version: A14



# SEMICONDUCTO

# TSM240N03CX 30V N-Channel Power MOSFET

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